NSN 5961-01-243-9214

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-243-9214 **Overall Length:** 2.800 inches **Terminal Length:** 1.250 inches **Overall Diameter:** 0.125 inches **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 17.0 breakdown voltage, instantaneous **Voltage Tolerance In Percent:** -20.0/+20.0 **Current Rating Per Characteristic:** 5.00 nanoamperes forward current, average peak **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Capacitance Rating In Picofarads:** 56.0 **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Yes - demil/mli

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